# VSMY98545ADS



Vishay Semiconductors

## High Power Infrared Emitting Diode, 850 nm, Surface Emitter Technology



#### DESCRIPTION

As part of the <u>SurfLight<sup>TM</sup></u> portfolio, the VSMY98545ADS is an infrared, 850 nm emitting diode based on surface emitter technology with high radiant power and high speed, molded in low thermal resistance SMD package with lens. A 42 mil chip provides outstanding radiant intensity and allows DC operation of the device up to 1 A. Superior ESD characteristics are ensured by an integrated Zener diode.

### FEATURES

- Package type: surface mount
- Double stack technology
- Package form: power QFN
- Dimensions (L x W x H in mm): 3.85 x 3.85 x 2.24
- Peak wavelength:  $\lambda_p = 850 \text{ nm}$
- Zener diode for ESD protection up to 2 kV
- High radiant power
- · High radiant intensity
- Angle of half intensity:  $\phi = \pm 45^{\circ}$
- Designed for high drive currents: up to 1 A (DC) and up to 5 A pulses
- Low thermal resistance: R<sub>thJP</sub> = 9 K/W
- Floor life: 168 h, MSL 3, according to J-STD-020
- Lead (Pb)-free reflow soldering
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### APPLICATIONS

- Infrared illumination for CMOS cameras (CCTV)
- Illumination for cameras (3D gaming)
- Machine vision

PRODUCT SUMMARY					
COMPONENT	l <sub>e</sub> (mW/sr)	φ <b>(deg)</b>	λ <sub>p</sub> (nm)	t <sub>r</sub> (ns)	
VSMY98545ADS	630	± 45	850	14	

Note

Test conditions see table "Basic Characteristics"

ORDERING INFORMATION				
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM	
VSMY98545ADS	Tape and reel	MOQ: 600 pcs, 600 pcs/reel	High power with lens	

#### Note

• MOQ: minimum order quantity

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V <sub>R</sub>	5	V	
Forward current		I <sub>F</sub>	1	A	
Peak forward current	$t_p/T = 0.5, t_p = 100 \ \mu s$	I <sub>FM</sub>	2	A	
Surge forward current	t <sub>p</sub> = 100 μs	I <sub>FSM</sub>	5	A	
Power dissipation		Pv	3.5	W	
Junction temperature		Tj	115	°C	
Operating temperature range		T <sub>amb</sub>	-40 to +85	°C	
Storage temperature range		T <sub>stg</sub>	-55 to +100	°C	
Soldering temperature	According to Fig. 7, J-STD-20	T <sub>sd</sub>	260	°C	
Thermal resistance junction / pin	JESD 51	R <sub>thJP</sub>	9	K/W	

Rev. 1.1, 27-Jan-2022

1 For technical questions, contact: <u>emittertechsupport@vishay.com</u> Document Number: 84390

RoHS COMPLIANT HALOGEN FREE

<u>GREEN</u> (5-2008)



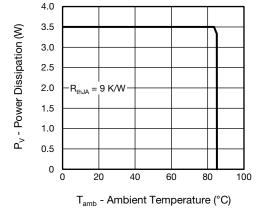
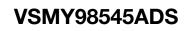


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature



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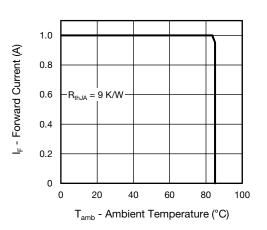


Fig. 2 - Forward Current Limit vs. Ambient Temperature

<b>BASIC CHARACTERISTICS</b> ( $T_{amb} = 25 \text{ °C}$ , unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	$I_{\rm F} = 1 \text{ A}, t_{\rm p} = 20 \text{ ms}$	V <sub>F</sub>	-	3.1	3.5	V
Temperature coefficient of V <sub>F</sub>	I <sub>F</sub> = 1 A		-	-3	-	mV/K
Reverse current	V <sub>R</sub> = 5 V	I <sub>R</sub>	-	-	10	μA
Junction capacitance	$V_R = 0 V, f = 1 MHz, E = 0 mW/cm^2$	CJ	-	130	-	pF
Radiant intensity	I <sub>F</sub> = 1 A, t <sub>p</sub> = 20 ms	l <sub>e</sub>	400	630	-	mW/sr
Radiant power	$I_F = 1 \text{ A}, t_p = 20 \text{ ms}$	фе	-	1340	-	mW
Temperature coefficient of $\boldsymbol{\phi}$	$I_{\rm F} = 1 \text{ A}, t_{\rm p} = 20 \text{ ms}$	$TK_{\phi}$	-	-0.3	-	%/K
Angle of half intensity		φ	-	± 45	-	deg
Peak wavelength	I <sub>F</sub> = 1 A	λ <sub>p</sub>	830	850	870	nm
Spectral bandwidth	I <sub>F</sub> = 1 A	Δλ	-	35	-	nm
Temperature coefficient of $\lambda_p$	$I_F = 1 \text{ A}, t_p = 20 \text{ ms}$	$TK_{\lambda p}$	-	0.3	-	nm/K
Rise time	I <sub>F</sub> = 1 A	t <sub>r</sub>	-	14	-	ns
Fall time	I <sub>F</sub> = 1 A	t <sub>f</sub>	-	17	-	ns

### BASIC CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

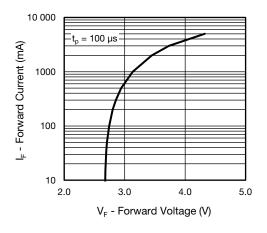


Fig. 3 - Forward Current vs. Forward Voltage

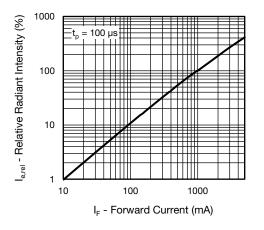


Fig. 4 - Relative Radiant Intensity vs. Forward Current

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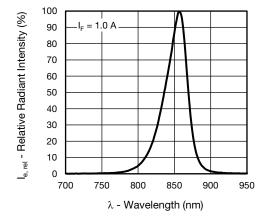
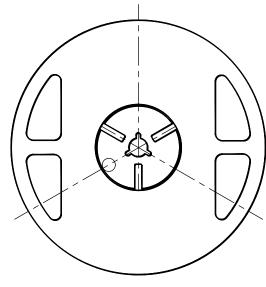
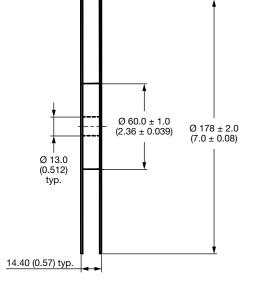


Fig. 5 - Relative Radiant Intensity vs. Wavelength

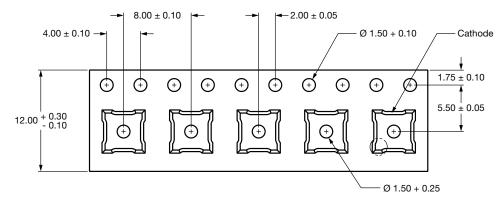
### TAPING DIMENSIONS in millimeters





#### Notes

- Empty component pockets sealed with top cover tape.
- 7 inch reel 600 pieces per reel.
- The maximum number of consecutive missing lamps is two.
- In accordance with ANSI/EIA 481-1-A-1994 specifications.



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30° l<sub>e, rel</sub> - Relative Radiant Intensity φ - Angular Displacement 40° 1.0 0.9 50° 0.8 60° 70° 0.7 80° 0.6 0.4 0.2 0

0°

Fig. 6 - Relative Radiant Intensity vs. Angular Displacement

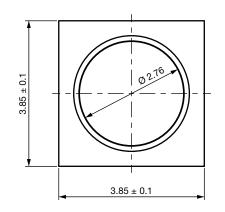
20°

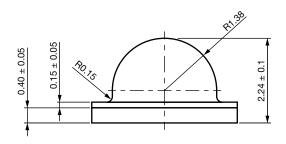
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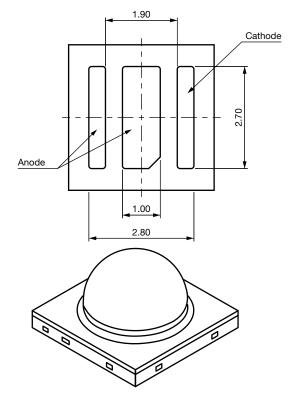
10°



#### **PACKAGE DIMENSIONS** in millimeters

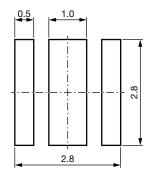






#### Notes

- Tolerance is ± 0.10 mm (0.004") unless otherwise noted.
- Specifications are subject to change without notice.

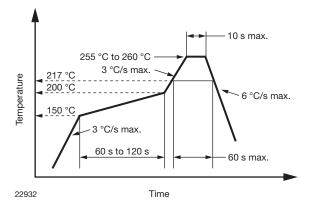


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### SOLDER PROFILE



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Fig. 7 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020

#### DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

#### FLOOR LIFE

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 168 h

Conditions:  $T_{amb} < 30\ ^\circ C,\ RH < 60\ \%$ 

Moisture sensitivity level 3, according to J-STD-020B

#### DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 °C (+ 5 °C), RH < 5 %.



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Revision: 01-Jan-2025

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